TLC7524C, TLC7524E, TLC7524I 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTERS

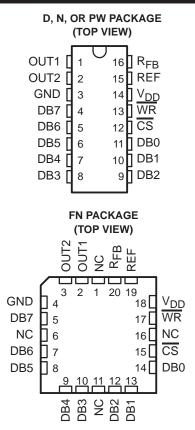
SLAS061D - SEPTEMBER 1986 - REVISED JUNE 2007

- Easily Interfaced to Microprocessors
- On-Chip Data Latches
- Monotonic Over the Entire A/D Conversion Range
- Segmented High-Order Bits Ensure Low-Glitch Output
- Interchangeable With Analog Devices AD7524, PMI PM-7524, and Micro Power Systems MP7524
- Fast Control Signaling for Digital Signal-Processor Applications Including Interface With TMS320
- CMOS Technology

KEY PERFORMANCE SPECIFICATIONS										
Resolution	8 Bits									
Linearity error	1/2LSB Max									
Power dissipation at V _{DD} = 5V	5mW Max									
Setting time	100ns Max									
Propagation delay time	80ns Max									

description

The TLC7524C, TLC7524E, and TLC7524I are CMOS, 8-bit, digital-to-analog converters (DACs) designed for easy interface to most popular microprocessors.



NC-No internal connection

The devices are 8-bit, multiplying DACs with input latches and load cycles similar to the write cycles of a random access memory. Segmenting the high-order bits minimizes glitches during changes in the most significant bits, which produce the highest glitch impulse. The devices provide accuracy to 1/2LSB without the need for thin-film resistors or laser trimming, while dissipating less than 5mW typically.

Featuring operation from a 5V to 15V single supply, these devices interface easily to most microprocessor buses or output ports. The 2- or 4-quadrant multiplying makes these devices an ideal choice for many microprocessor-controlled gain-setting and signal-control applications.

The TLC7524C is characterized for operation from 0°C to 70°C. The TLC7524I is characterized for operation from –25°C to +85°C. The TLC7524E is characterized for operation from –40°C to +85°C.



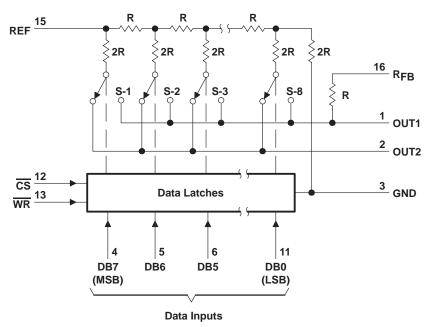
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functional block diagram



Terminal numbers shown are for the D or N package.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{DD}		–0.3V to 16.5V
Digital input voltage range, V _I		$-0.3V$ to $V_{DD} + 0.3V$
Reference voltage, V _{ref}		±25V
Peak digital input current, I ₁		10μΑ
Operating free-air temperature range, T _A : T	TLC7524C	0°C to +70°C
Т	TLC7524I	–25°C to +85°C
Т	TLC7524E	–40°C to +85°C
Storage temperature range, T _{stq}		–65°C to +150°C
Case temperature for 10 seconds, T _C : FN pa		
Lead temperature 1,6mm (1/16 inch) from ca		

package/ordering information

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

TLC7524C, TLC7524E, TLC7524I 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTERS

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recommended operating conditions

			V _{DD} = 5V			٧	LINUT		
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}			4.75	5	5.25	14.5	15	15.5	V
Reference voltage, V _{ref}				±10			±10		V
High-level input voltage, VIH			2.4			13.5			V
Low-level input voltage, V _{IL}					8.0			1.5	V
CS setup time, t _{SU(CS)}	40 40				ns				
CS hold time, th(CS)			0			0			ns
Data bus input setup time, t _{SU(D)}			25			25			ns
Data bus input hold time, th(D)			10			10			ns
Pulse duration, WR low, tw(WR)			40			40			ns
	TLC7524C		0		+70	0		+70	_
Operating free-air temperature, TA	TLC7524I		-25		+85	-25		+85	°C
	TLC7524E		-40		+85	-40		+85	

electrical characteristics over recommended operating free-air temperature range, V_{ref} = $\pm 10V$, OUT1 and OUT2 at GND (unless otherwise noted)

	DADAMETED		TEST COMPLETIONS	V	_{DD} = 5	٧	٧	OD = 15	V	
	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Ι _{ΙΗ}	High-level input curre	nt	$V_I = V_{DD}$			10			10	μΑ
I _{IL}	Low-level input currer	nt	V _I = 0			-10			-10	μΑ
	OUT1		DB0-DB7 at 0V, \overline{WR} , \overline{CS} at 0V, $V_{ref} = \pm 10V$			±400			±200	
Ilkg current		OUT2	DB0-DB7 at V_{DD} , \overline{WR} , \overline{CS} at 0V, $V_{ref} = \pm 10V$			±400			±200	nA
	DD Supply current Quiescent Standby		DB0-DB7 at V _{IH} min or V _{IL} max			1			2	mA
IDD			DB0-DB7 at 0V or V _{DD}			500			500	μΑ
k _{SVS}	Supply voltage sensit Δgain/ΔV _{DD}	ivity,	$\Delta V_{DD} = \pm 10\%$		0.01	0.16		0.005	0.04	%FSR/%
Ci	Input capacitance, DB0-DB7, WR, CS		V _I = 0			5			5	pF
		OUT1	DD0 DD7 -1 01/ WD 00 -1 01/			30			30	
	0	OUT2	DB0-DB7 at 0V, WR, CS at 0V			120			120	_
Co	Output capacitance	OUT1	DD0 DD7 -1.1/		120				120	pF
		OUT2	DB0–DB7 at V_{DD} , \overline{WR} , \overline{CS} at $0V$			30			30	
	Reference input impe (REF to GND)	dance		5		20	5		20	kΩ

TLC7524C, TLC7524E, TLC7524I 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTERS

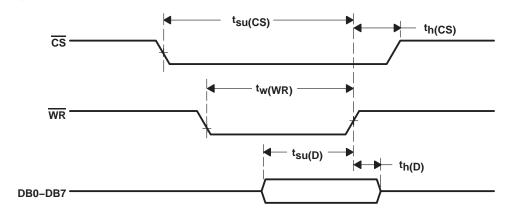
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operating characteristics over recommended operating free-air temperature range, $V_{ref} = \pm 10V$, OUT1 and OUT2 at GND (unless otherwise noted)

DADAMETED	TEGT CONDITIONS	\	/ _{DD} = 5V	1	٧			
PARAMETER	TEST CONDITIONS	MIN TYP MAX		MAX	MIN TYP		MAX	UNIT
Linearity error				±0.5			±0.5	LSB
Gain error	See Note 1			±2.5			±2.5	LSB
Settling time (to 1/2 LSB)	See Note 2			100			100	ns
Propagation delay from digital input to 90% of final analog output current	See Note 2			80			80	ns
Feedthrough at OUT1 or OUT2	$\frac{\text{Vref}}{\text{WR}} = \pm 10\text{V} \text{ (100kHz sinewave)}$ $\frac{\text{Vref}}{\text{WR}} = \pm 10\text{V} \text{ (100kHz sinewave)}$			0.5			0.5	%FSR
Temperature coefficient of gain	$T_A = +25^{\circ}C$ to MAX		±0.004			±0.001		%FSR/°C

NOTES: 1. Gain error is measured using the <u>internal feedback</u> resistor. Nominal full-scale range (FSR) = V_{ref} – 1LSB.
 OUT1 load = 100Ω, C_{ext} = 13pF, WR at 0V, CS at 0V, DB0 – DB7 at 0V to V_{DD} or V_{DD} to 0V.

operating sequence



voltage-mode operation

It is possible to operate the current-multiplying DAC in these devices in a voltage mode. In the voltage mode, a fixed voltage is placed on the current output terminal. The analog output voltage is then available at the reference voltage terminal. Figure 1 is an example of a current-multiplying DAC, which is operated in voltage mode.

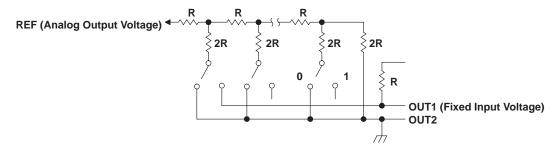


Figure 1. Voltage Mode Operation

The relationship between the fixed-input voltage and the analog-output voltage is given by the following equation:

$$V_O = V_I (D/256)$$

where

V_O = analog output voltage

 V_I = fixed input voltage

D = digital input code converted to decimal

In voltage-mode operation, these devices meet the following specification:

PARAMETER	TEST COND	MIN MAX	UNIT	
Linearity error at REF	$V_{DD} = 5V$, OUT1 = 2.5V, C	OUT2 at GND, $T_A = +25^{\circ}C$	1	LSB

The TLC7524C, TLC7524E, and TLC7524I are 8-bit multiplying DACs consisting of an inverted R-2R ladder, analog switches, and data input latches. Binary-weighted currents are switched between the OUT1 and OUT2 bus lines, thus maintaining a constant current in each ladder leg independent of the switch state. The high-order bits are decoded. These decoded bits, through a modification in the R-2R ladder, control three equally-weighted current sources. Most applications only require the addition of an external operational amplifier and a voltage reference.

The equivalent circuit for all digital inputs low is seen in Figure 2. With all digital inputs low, the entire reference current, I_{ref}, is switched to OUT2. The current source I/256 represents the constant current flowing through the termination resistor of the R-2R ladder, while the current source I_{Ikg} represents leakage currents to the substrate. The capacitances appearing at OUT1 and OUT2 are dependent upon the digital input code. With all digital inputs high, the off-state switch capacitance (30pF maximum) appears at OUT2 and the on-state switch capacitance (120pF maximum) appears at OUT1. With all digital inputs low, the situation is reversed as shown in Figure 2. Analysis of the circuit for all digital inputs high is similar to Figure 2; however, in this case, I_{ref} would be switched to OUT1.

The DAC on these devices interfaces to a microprocessor through the data bus and the $\overline{\text{CS}}$ and $\overline{\text{WR}}$ control signals. When $\overline{\text{CS}}$ and $\overline{\text{WR}}$ are both low, analog output on these devices responds to the data activity on the DB0–DB7 data bus inputs. In this mode, the input latches are transparent and input data directly affects the analog output. When either the $\overline{\text{CS}}$ signal or $\overline{\text{WR}}$ signal goes high, the data on the DB0–DB7 inputs are latched until the $\overline{\text{CS}}$ and $\overline{\text{WR}}$ signals go low again. When $\overline{\text{CS}}$ is high, the data inputs are disabled regardless of the state of the $\overline{\text{WR}}$ signal.

These devices are capable of performing 2-quadrant or full 4-quadrant multiplication. Circuit configurations for 2-quadrant or 4-quadrant multiplication are shown in Figure 3 and Figure 4. Table 1 and Table 2 summarize input coding for unipolar and bipolar operation respectively.

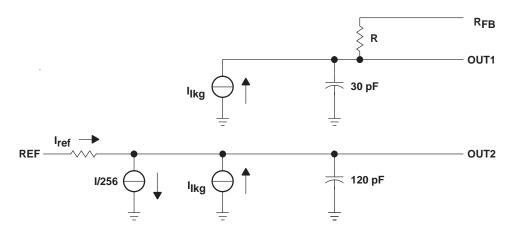
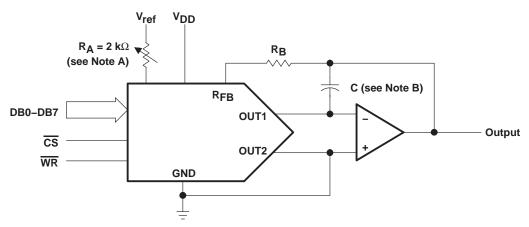
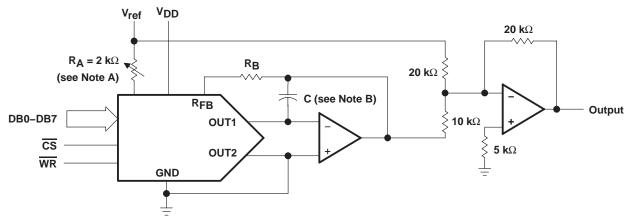


Figure 2. TLC7524 Equivalent Circuit With All Digital Inputs Low



- NOTES: A. $R_{\mbox{\scriptsize A}}$ and $R_{\mbox{\scriptsize B}}$ used only if gain adjustment is required.
 - B. C phase compensation (10-15 pF) is required when using high-speed amplifiers to prevent ringing or oscillation.

Figure 3. Unipolar Operation (2-Quadrant Multiplication)



- NOTES: A. RA and RB used only if gain adjustment is required.
 - B. C phase compensation (10-15 pF) is required when using high-speed amplifiers to prevent ringing or oscillation.

Figure 4. Bipolar Operation (4-Quadrant Operation)

Table 1. Unipolar Binary Code

	· · · · · · · · · · · · · · · · · · ·
DIGITAL INPUT (see Note 3)	ANALOG OUTPUT
MSB LSB	
11111111	-V _{ref} (255/256)
1000001	-V _{ref} (129/256)
10000000	$-V_{ref}$ (128/256) = $-V_{ref}$ /2
01111111	-V _{ref} (127/256)
0000001	-V _{ref} (1/256)
0000000	0

NOTE 3: LSB = $1/256 (V_{ref})$

Table 2. Bipolar (Offset Binary) Code

DIGITAL INP		ANALOG OUTPUT
MSB L	SB	
1111111	1	V _{ref} (127/128)
1000000	1	V _{ref} (1/128)
1000000	0	0
0111111	1	-V _{ref} (1/128)
0000000	1	-V _{ref} (127/128)
0000000	0	-V _{ref}

NOTE 4: LSB = $1/128 \text{ (V}_{ref})$



microprocessor interfaces

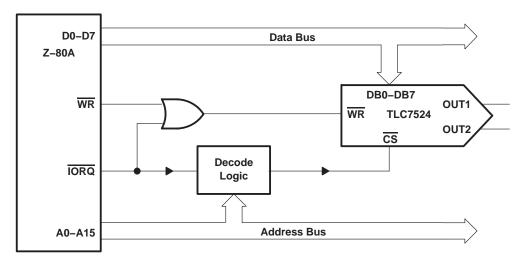


Figure 5. TLC7524: Z-80A Interface

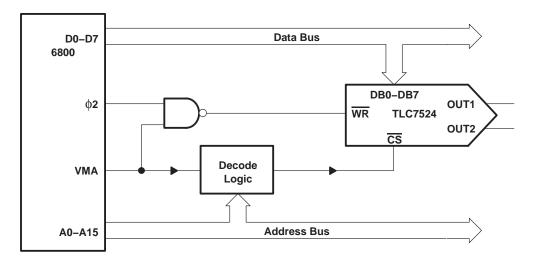


Figure 6. TLC7524: 6800 Interface

microprocessor interfaces (continued)

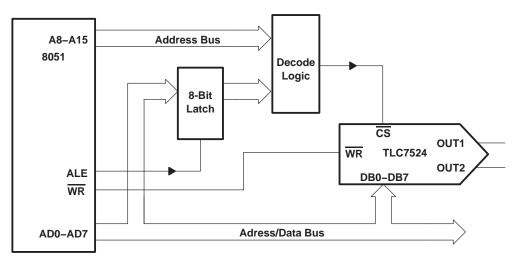


Figure 7. TLC7524: 8051 Interface

Revision History

DATE	REV	PAGE	SECTION	DESCRIPTION
6/07	D	Front Page	_	Deleted Available Options table.
0/07		2	_	Inserted Package/Ordering information.

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLC7524CD	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC7524C	Samples
TLC7524CDG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC7524C	Samples
TLC7524CDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC7524C	Samples
TLC7524CN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLC7524CN	Samples
TLC7524CNE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLC7524CN	Samples
TLC7524CNS	ACTIVE	SO	NS	16	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC7524	Samples
TLC7524CNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC7524	Samples
TLC7524CPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	P7524	Samples
TLC7524CPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	P7524	Samples
TLC7524ED	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLC7524E	Samples
TLC7524EDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLC7524E	Samples
TLC7524EN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TLC7524EN	Samples
TLC7524ID	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	TLC7524I	Samples
TLC7524IDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	TLC7524I	Samples
TLC7524IN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-25 to 85	TLC7524IN	Samples
TLC7524IPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	Y7524	Samples
TLC7524IPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-25 to 85	Y7524	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



PACKAGE OPTION ADDENDUM

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OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

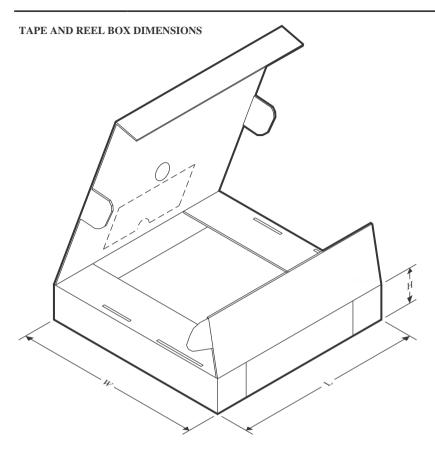


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC7524CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLC7524CNSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
TLC7524CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLC7524EDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLC7524IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLC7524IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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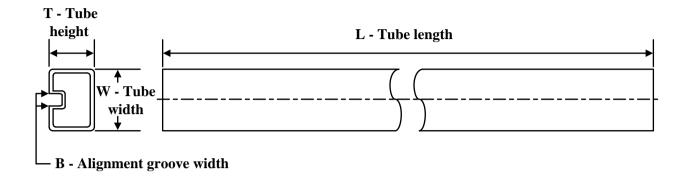
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ Length (mm)		Width (mm)	Height (mm)
TLC7524CDR	SOIC	D	16	2500	350.0	350.0	43.0
TLC7524CNSR	SO	NS	16	2000	356.0	356.0	35.0
TLC7524CPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
TLC7524EDR	SOIC	D	16	2500	350.0	350.0	43.0
TLC7524IDR	SOIC	D	16	2500	350.0	350.0	43.0
TLC7524IPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC7524CD	D	SOIC	16	40	505.46	6.76	3810	4
TLC7524CDG4	D	SOIC	16	40	505.46	6.76	3810	4
TLC7524CN	N	PDIP	16	25	506	13.97	11230	4.32
TLC7524CNE4	N	PDIP	16	25	506	13.97	11230	4.32
TLC7524CNS	NS	SOP	16	50	530	10.5	4000	4.1
TLC7524CPW	PW	TSSOP	16	90	530	10.2	3600	3.5
TLC7524ED	D	SOIC	16	40	505.46	6.76	3810	4
TLC7524EN	N	PDIP	16	25	506	13.97	11230	4.32
TLC7524ID	D	SOIC	16	40	505.46	6.76	3810	4
TLC7524IN	N	PDIP	16	25	506	13.97	11230	4.32
TLC7524IPW	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE

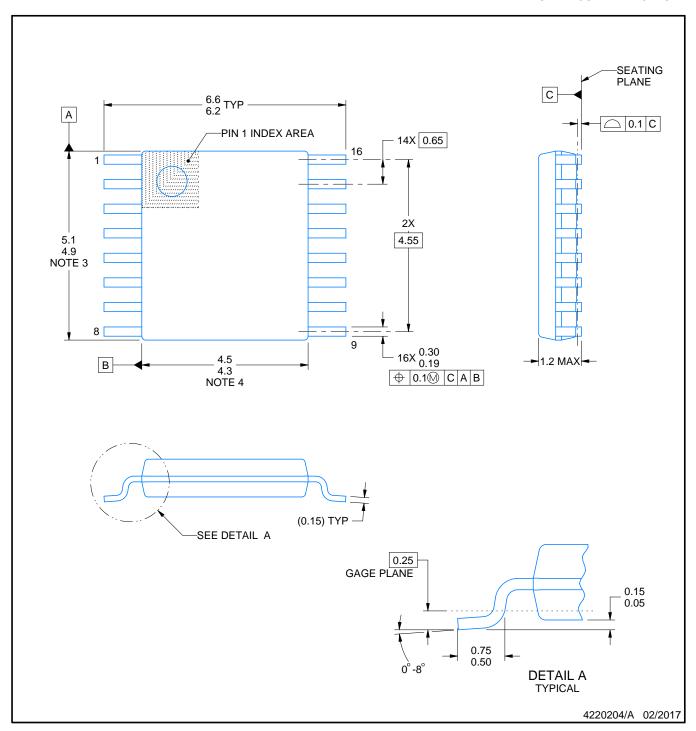


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



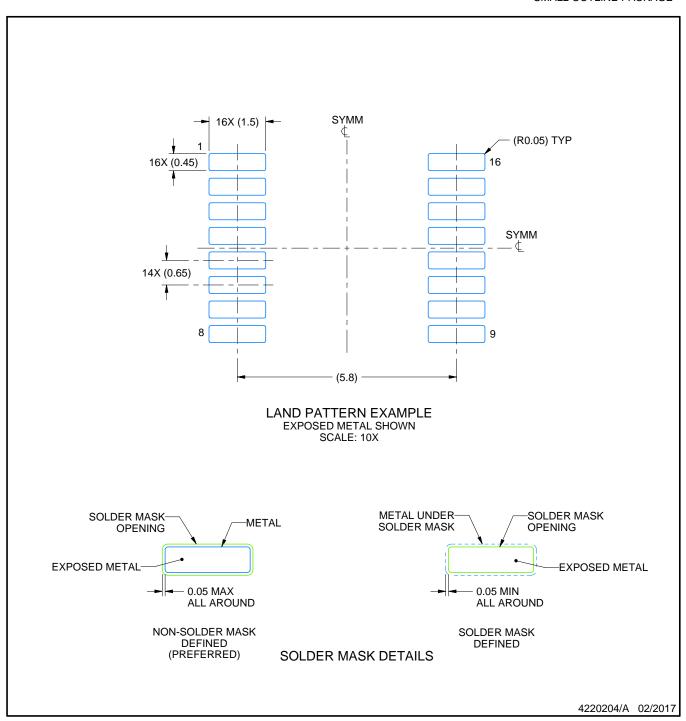
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



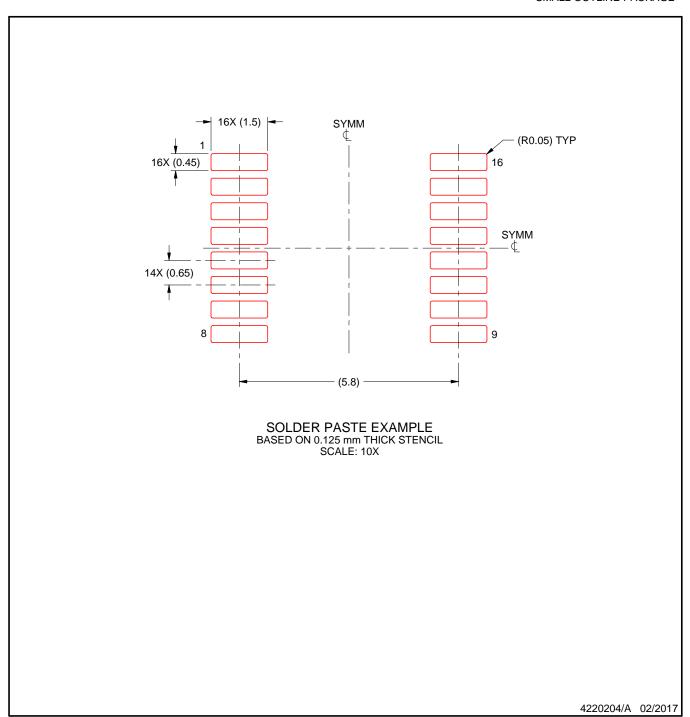
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

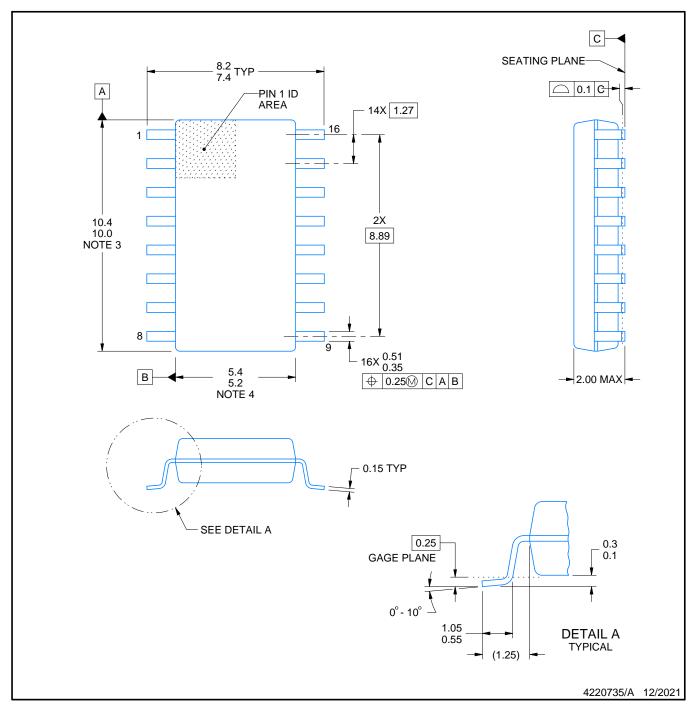


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



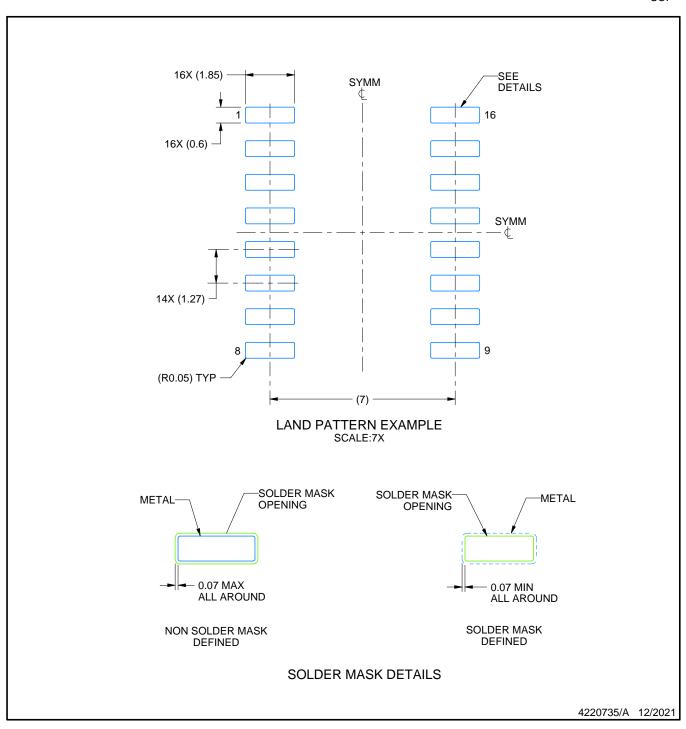
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF

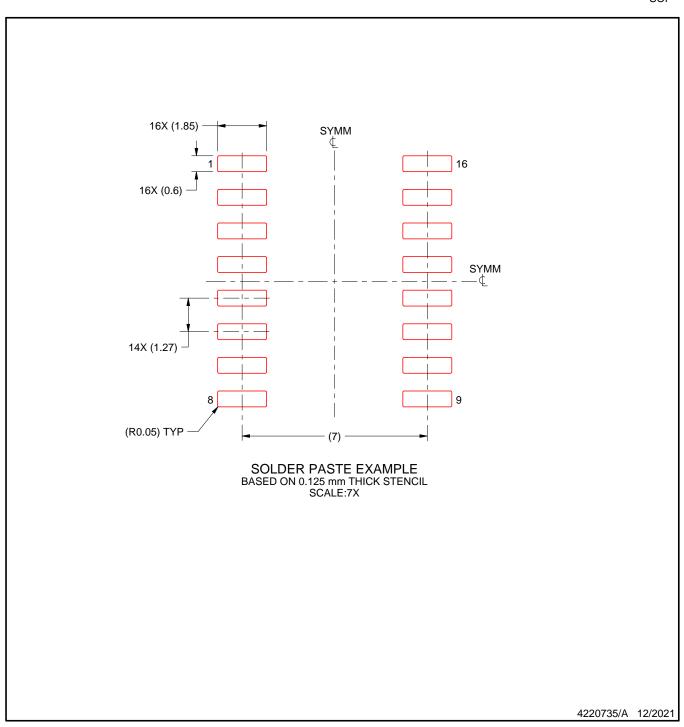


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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